L Number	Hits	Search Text	DB	Time stamp
1	59	"5956267"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:02
2	88533	trench$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:04
3	27	"6153443"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:11
4	63535	bit adj line$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:12
5	101	shield$3 adj bit adj line$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:13
6	13	(shield$3 adj bit adj line$1) and trench$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:28
7	1		USPAT	2004/09/07 11:25
8	1		USPAT	2004/09/07 11:25
9	1		USPAT	2004/09/07 11:25
10	1		USPAT	2004/09/07 11:26
11	1		USPAT	2004/09/07 11:26
12	1		USPAT	2004/09/07 11:26
13	15	clad$5 near (bit adj line$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:29
14	465629	shield$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:30
15	220	shield$4 near (bit adj line$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 11:30
16	60	(shield$4 near (bit adj line$1)) and trench$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:04
17	6	"6551852"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:17

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18	13	"6555858"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:20
19	0	blanket$5 adj tunnel adj layer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:21
20	0	blanket$5 adj barrierl adj layer	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:21
21	63	blanket$5 adj barrier adj layer$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:22
22	0	(blanket$5 adj barrier adj layer$1) and MRAM	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:22
23	3	(blanket$5 adj barrier adj layer$1) and magnetic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:27
24	27	"6153443"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:29
25	70664	barrier adj layer$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:30
26	8013	magnetic adj memory	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:30
27	3383	MRAM	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:30
28	533	(barrier adj layer$1) and (magnetic adj memory)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:31
29	638	(barrier adj layer$1) and MRAM	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:31

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30	796	((barrier adj layer$1) and (magnetic adj memory)) ((barrier adj layer$1) and MRAM)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:31
31	150	trench$3 and (((barrier adj layer$1) and (magnetic adj memory)) ((barrier adj layer$1) and MRAM))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:33
32	1785971	outside	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:33
34	1524	trench$3 near outside	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:34
35	4	(trench$3 near outside) and (((barrier adj layer$1) and (magnetic adj memory)) ((barrier adj layer$1) and MRAM))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 12:34
33	73	(trench$3 and (((barrier adj layer$1) and (magnetic adj memory)) ((barrier adj layer$1) and MRAM))) and outside	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 13:27
36	2	"6740947"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 13:33
37	2	"6693825"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 13:33
38	3	"6597049"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 13:34
39	7	"6661688"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/07 13:34

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Active
- L1: (59) "5956267"
- L2: (88533) trench$3
- L3: (27) "6153443"
- L4: (63535) bit adj line$1
- L5: (101) shield$3 adj bit adj line$1
- L6: (13) 5 and 2
- L7: (1) "5956267".PN.
- L9: (1) "5940319".PN.
- L13: (15) clad$5 near 4
- L14: (465629) shield$4
- L15: (220) 14 near 4
- L16: (60) 15 and 2
- L17: (6) "6551852"
- L18: (13) "6555858"
- L19: (0) blanket$5 adj tunnel adj layer
- L20: (0) blanket$5 adj barrierl adj layer
- L21: (63) blanket$5 adj barrier adj layer$1
- L22: (0) 21 and MRAM
- L23: (3) 21 and magnetic
- L24: (27) "6153443"
- L25: (70664) barrier adj layer$1
- L26: (8013) magnetic adj memory
- L27: (3383) MRAM
- L28: (533) 25 and 26
- L29: (638) 25 and 27
- L30: (796) 28 29
- L31: (150) 2 and 30
- L32: (1785971) outside
- L34: (1524) 2 near 32
- L35: (4) 34 and 30
- L33: (73) 31 and 32
- L36: (2) "6740947"
- L37: (2) "6693825"
- L38: (3) "6597049"
- L39: (7) "6661688"

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DBs: USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
Default operator: OR

31 and 32

Plurals
Highlight all hit terms initially

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BRS form   ISR form   Image   Text   HTML

	U	I	Document ID	Issue Date	Pages	Title	Current OR	Current XRef	Retrieval Cla	Inventor	S	C	P		S	Image 1
1			US 20040166618 A1	20040826	28	Low remanence flux concentrator for MRAM devices	438/197			Deak, James G.	☑					US 2004
2	☑		US 20040156232 A1	20040812	54	Magnetic memory	365/171			Saito, Yoshiaki et al.						US 2004
3			US 20040156231	20040812	21	Magnetic memory	365/158			Saito, Yoshiaki et al.						US 2004

Hits   Details   HTML

Ready   NUM